

CD405xB CMOS Single 8-Channel Analog Multiplexer or Demultiplexer With Logic-Level Conversion

1 Features

- Wide range of digital and analog signal levels:
 - Digital: 3V to 20V
 - Analog: ≤ 20V_{P-P}
- Single supply range: 3V to 20V (performance degrades for VDD < 3V)
- Dual Supply range: ± 3V to ± 10V
- Low ON resistance, 125Ω (typical) over input range for $V_{DD} = 15V$
- Low channel leakage of $\pm 10pA$ (typical) at $V_{DD} =$ 15V
- Low guiescent power dissipation: 0.2µW (typical)
- Break-before-make switching eliminates channel overlap
- Bidirectional signal path
- ESD protection HBM: 3000V, CDM: 2000V
- Pin compatible with industry standard 4051 muxes

2 Applications

- Analog and digital multiplexing and demultiplexing
- Analog to digital and digital to analog conversion
- Signal gating
- **Factory automation**
- **Televisions**
- **Appliances**
- Consumer audio
- Programmable logic circuits
- Sensors

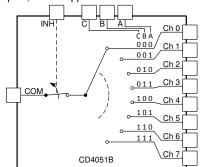
3 Description

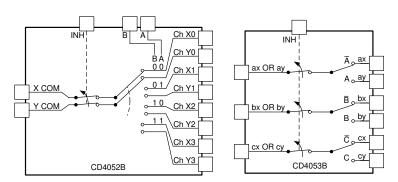
The CD405xB analog multiplexers and demultiplexers are digitally-controlled analog switches having low ON impedance and very low OFF leakage current. These multiplexer circuits dissipate extremely low quiescent power over the full $V_{DD} - V_{SS}$ and $V_{DD} - V_{EE}$ supplyvoltage ranges, independent of the logic state of the control signals.

Package Information

PART NUMBER	PACKAGE (1)	PACKAGE SIZE ⁽²⁾		
	J (CDIP, 16)	19.50mm × 6.92mm		
	N (PDIP, 16)	19.3mm × 9.4mm		
CD405xB	D (SOIC, 16)	9.9mm × mm		
	NS (SOP, 16)	10.2mm × 7.8mm		
	PW (TSSOP, 16)	5mm × 6.4mm		

- (1) For all available packages, see the orderable addendum at the end of the data sheet.
- The package size (length × width) is a nominal value and includes pins, where applicable.





Functional Diagrams of CD4051B



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4 Pin Configuration and Functions

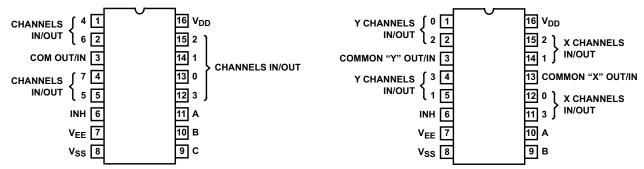


Figure 4-1. CD4051B E, M, NS, and PW Package, 16-Pin PDIP, CDIP, SOIC, SOP, and TSSOP (Top View)

Figure 4-2. CD4052B E, M, NS, and PW Package, 16-Pin PDIP, CDIP, SOP, and TSSOP (Top View)

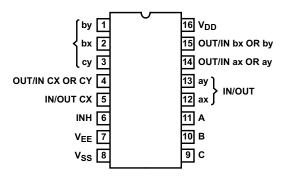


Figure 4-3. CD4053B E, M, NS, and PW Package, 16-Pin PDIP, CDIP, SOP, and TSSOP (Top View)

Table 4-1. Pin Functions CD4051B

	PIN	TYPE ⁽¹⁾	DESCRIPTION
NO.	NAME	IIPE(/	DESCRIPTION
1	CH 4 IN/OUT	I/O	Channel 4 in/out
2	CH 6 IN/OUT	I/O	Channel 6 in/out

NO.	NAME		
1	CH 4 IN/OUT	I/O	Channel 4 in/out
2	CH 6 IN/OUT	I/O	Channel 6 in/out
3	COM OUT/IN	I/O	Common out/in
4	CH 7 IN/OUT	I/O	Channel 7 in/out
5	CH 5 IN/OUT	I/O	Channel 5 in/out
6	INH	I	Disables all channels. See Table 7-1.
7	V _{EE}	_	Negative power input
8	V _{SS}	_	Ground
9	С	I	Channel select C. See Table 7-1.
10	В	I	Channel select B. See Table 7-1.
11	A	I	Channel select A. See Table 7-1.
12	CH 3 IN/OUT	I/O	Channel 3 in/out
13	CH 0 IN/OUT	I/O	Channel 0 in/out
14	CH 1 IN/OUT	I/O	Channel 1 in/out
15	CH 2 IN/OUT	I/O	Channel 2 in/out
16	V _{DD}	_	Positive power input

I = input, O = output



Table 4-2. Pin Functions CD4052B

PIN		TYPE ⁽¹⁾	DESCRIPTION				
NO.	NAME	ITPE	DESCRIPTION				
1	Y CH 0 IN/OUT	I/O	Channel Y0 in/out				
2	Y CH 2 IN/OUT	I/O	Channel Y2 in/out				
3	Y COM OUT/IN	I/O	Y common out/in				
4	Y CH 3 IN/OUT	I/O	Channel Y3 in/out				
5	Y CH 1 IN/OUT	I/O	Channel Y1 in/out				
6	INH	I	Disables all channels. See Table 7-1.				
7	V _{EE}	_	Negative power input				
8	V _{SS}	_	Ground				
9	В	I	Channel select B. See Table 7-1.				
10	A	1	Channel select A. See Table 7-1.				
11	X CH 3 IN/OUT	I/O	Channel X3 in/out				
12	X CH 0 IN/OUT	I/O	Channel X0 in/out				
13	X COM IN/OUT	I/O	X common out/in				
14	X CH 1 IN/OUT	I/O	Channel in/out				
15	X CH 2 IN/OUT	I/O	Channel in/out				
16	V_{DD}	_	Positive power input				

(1) I = input, O = output

Table 4-3. Pin Functions CD4053B

PIN		TYPE ⁽¹⁾	DESCRIPTION			
NO.	NAME	ITPE(*)	DECOMP HON			
1	BY IN/OUT	I/O	B channel Y in/out			
2	BX IN/OUT	I/O	B channel X in/out			
3	CY IN/OUT	I/O	C channel Y in/out			
4	CX OR CY OUT/IN	I/O	C common out/in			
5	CX IN/OUT	I/O	C channel X in/out			
6	INH	I	Disables all channels. See Table 7-1.			
7	V _{EE}	_	Negative power input			
8	V _{SS}	_	Ground			
9	С	I	Channel select C. See Table 7-1.			
10	В	I	Channel select B. See Table 7-1.			
11	A	I	Channel select A. See Table 7-1.			
12	AX IN/OUT	I/O	A channel X in/out			
13	AY IN/OUT	I/O	A channel Y in/out			
14	AX OR AY OUT/IN	I/O	A common out/in			
15	BX OR BY OUT/IN	I/O	B common out/in			
16	V _{DD}	_	Positive power input			

(1) I = input, O = output



5 Specifications

5.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)(1) (2)

			MIN	MAX	UNIT
	Supply Voltage	V+ to V-, Voltages Referenced to V _{SS} Terminal	-0.5	20	V
	DC Input Voltage		-0.5	V _{DD} +0.5	V
	DC Input Current	Any One Input	-10	10	mA
T _{JMAX1}	Maximum junction tempe	rature, ceramic package		175	°C
T _{JMAX2}	Maximum junction temperature, plastic package			150	°C
T _{stg}	Storage temperature		-65	150	°C

⁽¹⁾ Stresses beyond those listed under Absolute Maximum Rating may cause permanent damage to the device. These are stress ratings only, which do not imply functional operation of the device at these or any other conditions beyond those indicated under Recommended Operating Condition. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

5.2 ESD Ratings

			VALUE	UNIT
	Human body model (HBM), per ANSI/ESDA/ JEDEC JS-001, all pins ⁽¹⁾	±3000	V	
V _(ESD)	Electrostatic discharge	Charged device model (CDM), per JEDEC specification JESD22-C101, all pins ⁽²⁾	±2000	V

⁽¹⁾ JEDEC document JEP155 states that 500V HBM allows safe manufacturing with a standard ESD control process.

5.3 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)

	MIN	NOM MAX	UNIT
Temperature Range	– 55	125	· · · ·

5.4 Thermal Information

THERMAL METRIC ⁽¹⁾		CD405x					
		E (PDIP)	E (PDIP) M (SOIC) NS (SOP) PW (TSSOP)				
		16 PINS	16 PINS	16 PINS	16 PINS		
$R_{\theta JA}$	Junction-to-ambient thermal resistance	67	73	64	116.5	°C/W	

⁽¹⁾ For more information about traditional and new thermal metrics, see the Semiconductor and IC Package Thermal Metrics application report.

⁽²⁾ All voltages are with respect to ground, unless otherwise specified.

⁽²⁾ JEDEC document JEP157 states that 250V CDM allows safe manufacturing with a standard ESD control process.



5.5 Electrical Characteristics

Over operating free-air temperature range, $V_{SUPPLY} = \pm 5V$, and $R_L = 100\Omega$, (unless otherwise noted)⁽¹⁾

PARAMETER			TEST COND	ITIONS		MIN	TYP	MAX	UNIT
SIGNAL INPUTS (VIS) AND OUTPUT	S (Vos)								
	V _{IS} (V)	V _{EE} (V)	V _{SS} (V)	V _{DD} (V)	TEMP				
					–55°C			60	
		0V			-40°C			60	
			0V	5V	25°C		17	60	
					85°C			150	
					125°C			150	
					–55°C			60	
					-40°C			60	
		0V	0V	10V	25°C		18	60	
					85°C			300	
Quiescent Device Current, I _{DD} Max					125°C			300	
, , , , , , , , , , , , , , , , , , , ,					–55°C			60	μA
					-40°C			60	
		0V	0V	15V	25°C		18	60	
					85°C			600	
					125°C			600)
					–55°C			100	
					-40°C			100	
		0V	0V	20V	25°C		18	100	
					85°C			3000	
					125°C			3000	
					-55°C			800	
					–40°C			850	
		0V	0V	5V	25°C		470	1050	-
					85°C			1200	
					125°C			1300	
					-55°C			310	
Drain to Source ON Resistance r _{ON}					-40°C			300	
Max		0V	0V	10V	25°C		180	400	Ω
$0 \le V_{IS} \le V_{DD}$					85°C			520	
					125°C			550	_
					–55°C			200	
					-40°C			210)
		0V	0	15V	25°C		125	240	
					85°C			300	
					125°C			300	
Change in ON Resistance		0V	0V	5V			15		
(Between Any Two Channels),		0V	0V	10V	25°C		10		Ω
ΔR_{ON}		0V	0V	15V			5		



5.5 Electrical Characteristics (continued)

Over operating free-air temperature range, $V_{SUPPLY} = \pm 5V$, and $R_L = 100\Omega$, (unless otherwise noted)⁽¹⁾

PARAMETER				TEST CONDITIONS					MAX	UNIT
							–55°C		± 100	
						–40°C		± 100		
OFF Channel Leakage Current: Any Channel OFF (Max)						25°C	± 0.3	± 100 (2)		
	Channels OFF (COMMC	N		0V	0V	18V	85°C		± 1000 (2)	nA
							125°C		± 1000 (2)	
	annel Leakage Current: A	Any	5 or 0	-5V	0V	10.5V	85°C		± 300	
	Channel ON (Max) or ALL Channels ON (COMMON OUT/IN) (Max)		5	0V	0V	18V	85°C		± 300	nA
	Input, C _{IS}							5		
	Output, C _{OS}	CD4 051					30)		
Capaci tance	Output, C _{OS}	CD4 052		0V	0V 0V	0V 10V	10V 25°C	18	3	pF
	Output, C _{OS}	CD4 053						9	9	
	Feed through, C _{IOS}	•						0.2	2	
				R _L = 200kg	Ω	5V		30	0 60	
Prop De	elay		V_{DD}	$C_L = 50pF$		10V	25°C	15	5 30	ns
				$t_{r}, t_{f} = 20 \text{ns}$;	15V		10	20	



5.5 Electrical Characteristics (continued)

Over operating free-air temperature range, $V_{SUPPLY} = \pm 5V$, and $R_L = 100\Omega$, (unless otherwise noted)⁽¹⁾

	PARAMETER			TEST COND	DITIONS		MIN	TYP	MAX	UNIT
CONT	ROL (ADDRESS OR INHIBIT), V	3								
						–55°C		8.0		
						-40°C		0.8		
					5V	25°C			0.8	
						85°C		0.8		
						125°C		0.8		
						-55°C		0.8		
						-40°C		0.8		
nput L	ow Voltage, V _{IL} , Max				10V	25°C			0.8	V
						85°C		0.8		
						125°C		0.8		
						–55°C		0.8		
						-40°C		0.8		
					15V	25°C			0.8	
						85°C		0.8		
						125°C		0.8		
						–55°C		3.5		
						-40°C		3.5		┪ ┃
					5V	25°C	3.5			
						85°C		3.5		1
						125°C		3.5		
						–55°C		7		V
						-40°C		7		
nput H	ligh Voltage, V _{IH} , Min				10V	25°C	7			
•	3 7 117					85°C		7		
						125°C		7		
						-55°C		11		
						-40°C		11		
					15V	25°C	11			
						85°C		11		
						125°C		11		
						–55°C			±1	
						-40°C			±1	
nput c	urrent, I _{IN} (Max)	V _{IN} = 0, 18			18V	25°C		±0.6	±1	μA
•	, IIV ()	"1"				85°C			±1	'
						125°C			±1	
			0V	0V	5V			450	720	
Propa gation	Address-to-Signal OUT (Channels ON or OFF) (See	t _r , t _f = 20ns,	0V	0V	10V			160	320	
Delay	Figure 10, Figure 11, and	$C_L = 50 pF$,	0V	0V	15V			120	240	ns
Гime	Figure 15)	$R_L = 10k\Omega$	_5V	0V	5V			225	450	
			0V	0V	5V			400	720	
Propa	Inhibit to Signal OUT (Charrel	t _r , t _f = 20ns,	0V	0V	10V			160	320	
gation Delay	Inhibit-to-Signal OUT (Channel Turning ON) (See Figure 11)	$C_L = 50 pF,$	0V	0V	15V			120		ns l
Delay Fime		$R_L = 1k\Omega$		100	100			.20		



5.5 Electrical Characteristics (continued)

Over operating free-air temperature range, $V_{SUPPLY} = \pm 5V$, and $R_L = 100\Omega$, (unless otherwise noted)⁽¹⁾

	PARAMETER		TEST CONDITIONS						MAX	UNIT
Propa gation	Inhibit-to-Signal OUT (Channel Turning OFF) (See Figure 17)	t_{r} , t_{f} = 20ns, C_{L} = 50pF, R_{L} = 10k Ω	0V	0V	5V			200	450	
			0V	0V	10V			90	210	no
Delay			0V	0V	15V			70	160	ns
Time			-10V	0V	5V			130	300	
Input C	Input Capacitance, C _{IN} (Any Address or Inhibit Input)			0V	5V	25°C		5	7.5	pF

⁽¹⁾

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Peak-to-Peak voltage symmetrical about $(V_{DD}-V_{EE})$ / 2. Determined by minimum feasible leakage measurement for automatic testing.



5.6 AC Performance Characteristics

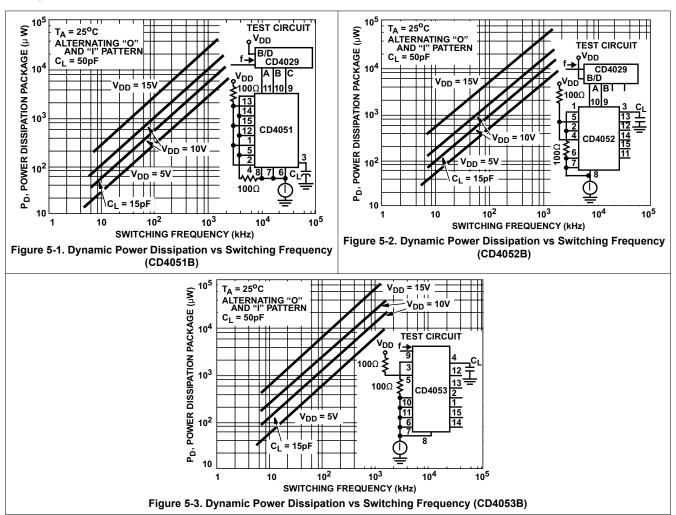
 V_{DD} = +15V, V_{SS} = V_{EE} = 0V, T_A = 25°C (unless otherwise noted)

PARAMETER			TEST	CONDITIONS		TYP	UNIT	
	V _{IS} (V)	V _{DD} (V)	R _L (kΩ)					
		10	1		CD4053	30		
Cutoff (–3dB)	5 ⁽¹⁾	10	1	V _{OS} at Common OUT/IN	CD4052	25		
Frequency Channel ON (Sine Wave		10 1			CD4051	20	MHz	
Input)	$V_{EE} = V_{SS}$, 20Log(V_{OS}/V	_{IS}) = –3dB	•	V _{OS} at Any Channel		60		
	2 ⁽¹⁾	5	10			0.3%	%	
Total Harmonic	3 ⁽¹⁾	10	10			0.2%		
Distortion, THD	5 ⁽¹⁾	15	10			0.12%		
	V _{EE} = V _{SS} , f _{IS}	= 1kHz Sine	Wave					
-40dB Feedthrough Frequency (All Channels OFF)	5 ⁽¹⁾	10	1	V 10 OUT(IN	CD4053	8		
				V _{OS} at Common OUT/IN	CD4052	10	MHz	
	V _{EE} = V _{SS} , 20Log(V _{OS} /V _{IS}) = –40d				CD4051	12		
		13/		V _{OS} at Any Channel		8		
	5 ⁽¹⁾	10	1			3		
			•	Datus an Sections	Measured on Common	6		
–40dB Signal Crosstalk Frequency	$V_{EE} = V_{SS}$, 20Log(V_{OS}/V) — 2dD		Between Sections, CD4052 Only	Measured on Any Channel	10	MHz	
	ZOLOG(V _{OS} /V	_{IS}) – –3ub		Between Any Two	In Pin 2, Out Pin 14	2.5		
				Sections, CD4053 Only	In Pin 15, Out Pin 14	6		
Address-or-Inhibit-to-		10	10 ⁽²⁾		'	65	${\sf mV}_{\sf PEAK}$	
Signal Crosstalk	$V_{EE} = 0, V_{SS}$ $V_{CC} = V_{DD} - 0$	= 0, t _r , t _f = 20 V _{SS} (Square)	Ons, mVPEAK Wave)			65	${\sf mV}_{\sf PEAK}$	

⁽¹⁾ Peak-to-Peak voltage symmetrical about (V_{DD} - V_{EE}) / 2. (2) Both ends of channel.



5.7 Typical Characteristics



6 Parameter Measurement Information

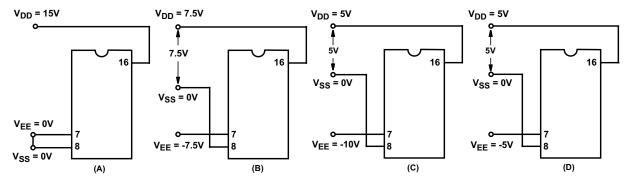


Figure 6-1. Typical Bias Voltages

Note

The ADDRESS (digital-control inputs) and INHIBIT logic levels are: $0 = V_{SS}$ and $1 = V_{DD}$. The analog signal (through the TG) may swing from V_{EE} to V_{DD} .



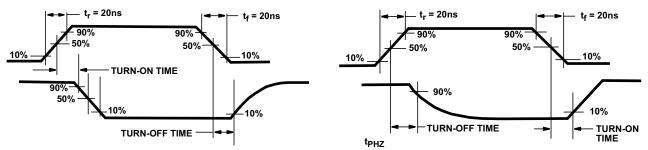


Figure 6-2. Waveforms, Channel Being Turned ON Figure 6-3. Waveforms, Channel Being Turned OFF $(R_L = 1k\Omega)$ $(R_L = 1k\Omega)$

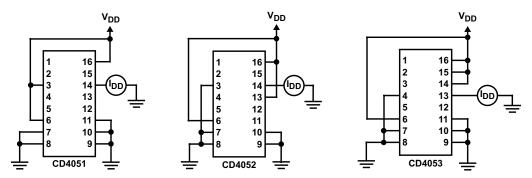


Figure 6-4. OFF Channel Leakage Current - Any Channel OFF

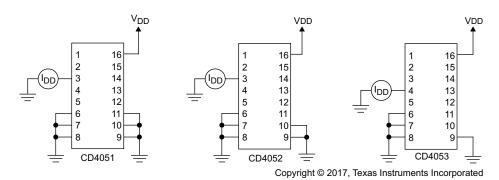


Figure 6-5. On Channel Leakage Current - Any Channel On

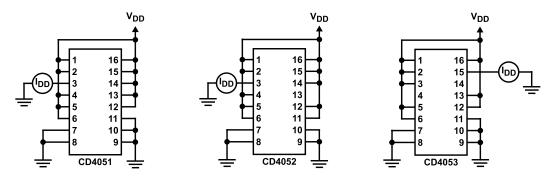


Figure 6-6. OFF Channel Leakage Current – All Channels OFF

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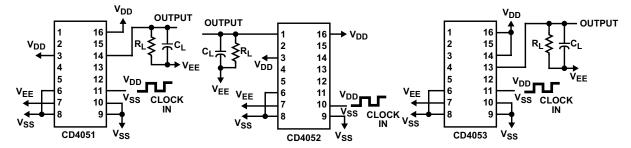


Figure 6-7. Propagation Delay – Address Input to Signal Output

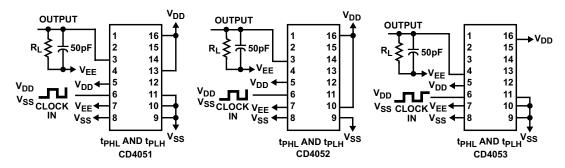


Figure 6-8. Propagation Delay – Inhibit Input to Signal Output

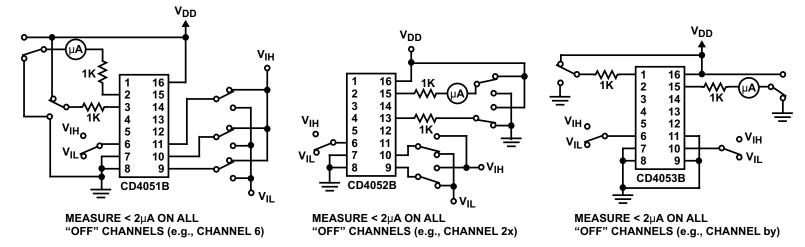


Figure 6-9. Input Voltage Test Circuits (Noise Immunity)

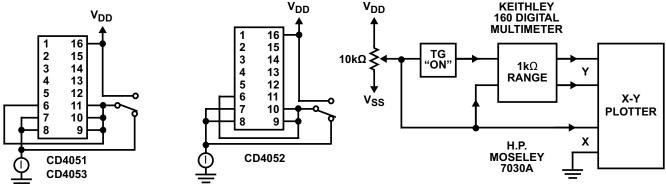


Figure 6-10. Quiescent Device Current

Figure 6-11. Channel ON Resistance Measurement Circuit



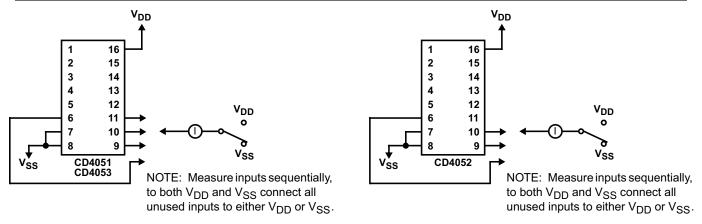


Figure 6-12. Input Current

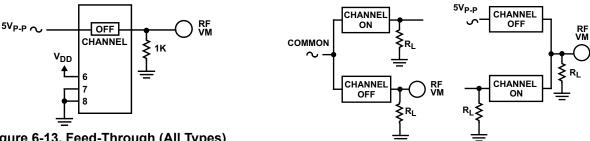


Figure 6-13. Feed-Through (All Types)

Figure 6-14. Crosstalk Between Any Two Channels (All Types)

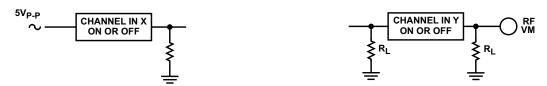
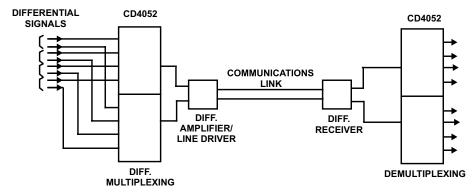


Figure 6-15. Crosstalk Between Duals or Triplets (CD4052B, CD4053B)



 $\textbf{Special Considerations:} \ \text{In applications where separate power sources are used to drive } \ V_{DD} \ \text{and the signal inputs, the } \ V_{DD} \ \text{current}$ capability should exceed V_{DD}/R_L (R_L = effective external load). This provision avoids permanent current flow or clamp action on the V_{DD} supply when power is applied or removed from the CD4051B, CD4052B or CD4053B.

Figure 6-16. Typical Time-Division Application of the CD4052B



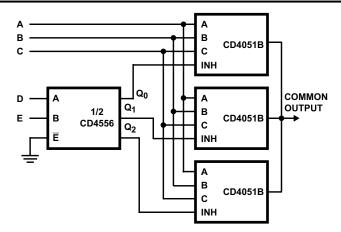


Figure 6-17. 24-to-1MUX Addressing

7 Detailed Description

7.1 Overview

The CD4051B device is a single 8-channel multiplexer having three binary control inputs, A, B, and C, and an inhibit input. The three binary signals select 1 of 8 channels to be turned on, and connect one of the 8 inputs to the output.

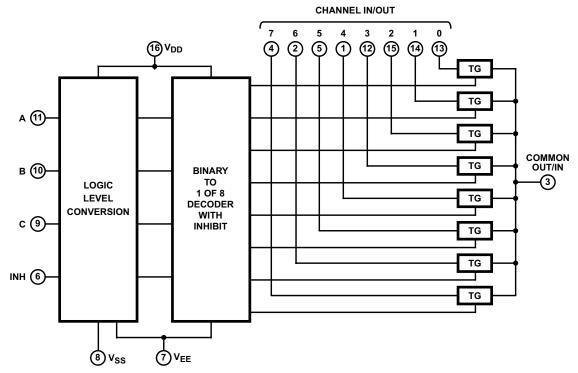
The CD4052B device is a differential 4-channel multiplexer having two binary control inputs, A and B, and an inhibit input. The two binary input signals select 1 of 4 pairs of channels to be turned on and connect the analog inputs to the outputs.

The device is a triple 2-channel multiplexer having three separate digital control inputs, A, B, and C, and an inhibit input. Each control input selects one of a pair of channels which are connected in a single-pole, double-throw configuration.

When these devices are used as demultiplexers, the CHANNEL IN/OUT terminals are the outputs and the COMMON OUT/IN terminals are the inputs.

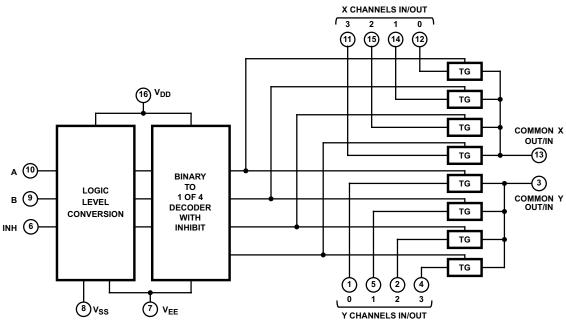


7.2 Functional Block Diagrams



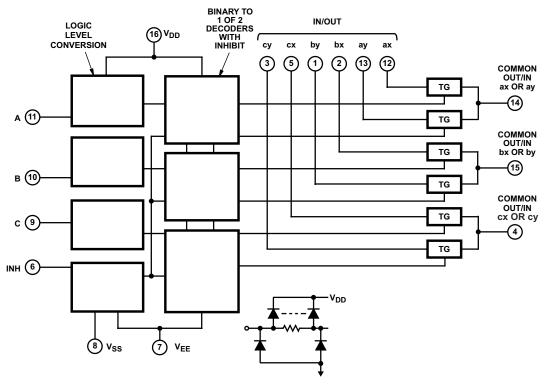
All inputs are protected by standard CMOS protection network.

Figure 7-1. Functional Block Diagram, CD4051B



All inputs are protected by standard CMOS protection network.

Figure 7-2. Functional Block Diagram, CD4052B



All inputs are protected by standard CMOS protection network.

Figure 7-3. Functional Block Diagram, CD4053B

7.3 Feature Description

The CD405xB line of multiplexers and demultiplexers can accept a wide range of digital and analog signal levels. Digital signals range from 3V to 20V, and analog signals are accepted at levels \leq 20V. The devices have low ON resistance, typically 125Ω over $15V_{P-P}$ signal input range for $V_{DD} - V_{EE}$ = 18V. This feature allows for very little signal loss through the switch.

The CD405xB devices also have high OFF resistance, which keeps from the devices from wasting power when the switch is in the OFF position, with typical channel leakage of ± 100 pA at $V_{DD} - V_{EE} = 18$ V.

Binary address decoding on the chip makes channel selection simple. When channels are changed, a break-before-make system eliminates channel overlap.



7.4 Device Functional Modes

Table 7-1. Truth Table (1)

	IN	PUT STATES		ON OUANNEL (O)
INHIBIT	С	В	Α	ON CHANNEL(S)
CD4051B	'			
0	0	0	0	0
0	0	0	1	1
0	0	1	0	2
0	0	1	1	3
0	1	0	0	4
0	1	0	1	5
0	1	1	0	6
0	1	1	1	7
1	X	Х	X	None
D4052B				
0		0	0	0x, 0y
0		0	1	1x, 1y
0		1	0	2x, 2y
0		1	1	3x, 3y
1		Х	X	None
D4053B				
0	X	X	0	ax
0	Х	X	1	ay
0	Х	0	X	bx
0	X	1	X	by
0	0	X	X	cx
0	1	X	X	су
1	Х	X	X	None

⁽¹⁾ X = Do not care



8 Application and Implementation

Note

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes, as well as validating and testing their design implementation to confirm system functionality.

8.1 Application Information

The CD405xB multiplexers and demultiplexers can be used for a wide variety of applications.

8.2 Typical Application

One application of the CD4051B is to use it in conjunction with a microcontroller to poll a keypad. Figure 8-1 shows the basic schematic for such a polling system. The microcontroller uses the channel select pins to cycle through the different channels while reading the input to see if a user is pressing any of the keys. This application is a very robust setup, allowing for multiple simultaneous key-presses with very little power consumption. This setup also uses very few pins on the microcontroller. The down side of polling is that the microcontroller must continually scan the keys for a press and can do little else during this process.

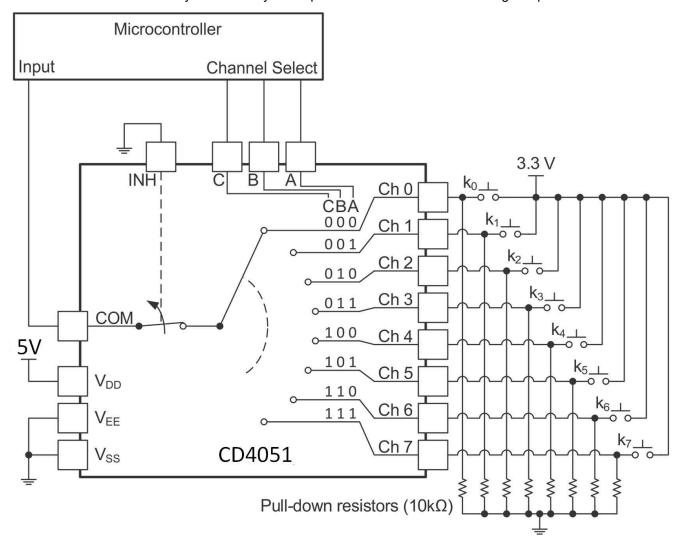


Figure 8-1. The CD4051B Being Used to Help Read Button Presses on a Keypad

8.2.1 Design Requirements

These devices use CMOS technology and have balanced output drive. Take care to avoid bus contention because it can drive currents that would exceed maximum limits. The high drive will also create fast edges into light loads, so routing and load conditions should be considered to prevent ringing.

8.2.2 Detailed Design Procedure

- 1. Recommended Input Conditions:
 - For switch time specifications, see propagation delay times in *Electrical Characteristics*.
 - Inputs should not be pushed more than 0.5V above V_{DD} or below V_{EE}.
 - For input voltage level specifications for control inputs, see V_{IH} and V_{IL} in *Electrical Characteristics*.
- 2. Recommended Output Conditions:
 - Outputs should not be pulled above V_{DD} or below V_{EE}.
- 3. Input or output current consideration:
 - The CD405xB series of parts do not have internal current drive circuitry and thus cannot sink or source current. Any current will be passed through the device.

8.2.3 Application Curve

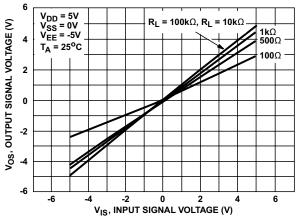


Figure 8-2. ON Characteristics for 1 of 8 Channels (CD4051B)

8.3 Power Supply Recommendations

The power supply can be any voltage between the minimum and maximum supply voltage rating located in the *Electrical Characteristics*.

Each V_{CC} terminal should have a good bypass capacitor to prevent power disturbance. For devices with a single supply, a $0.1\mu F$ bypass capacitor is recommended. If there are multiple pins labeled V_{CC} , then a $0.01\mu F$ or $0.022\mu F$ capacitor is recommended for each V_{CC} because the V_{CC} pins will be tied together internally. For devices with dual supply pins operating at different voltages, for example V_{CC} and V_{DD} , a $0.1\mu F$ bypass capacitor is recommended for each supply pin. It is acceptable to parallel multiple bypass capacitors to reject different frequencies of noise. $0.1\mu F$ and $1\mu F$ capacitors are commonly used in parallel. The bypass capacitor should be installed as close to the power terminal as possible for best results.

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8.4 Layout

8.4.1 Layout Guidelines

Reflections and matching are closely related to loop antenna theory, but different enough to warrant their own discussion. When a PCB trace turns a corner at a 90° angle, a reflection can occur. This reflection is primarily due to the change of width of the trace. At the apex of the turn, the trace width is increased to 1.414 times its width. This upsets the transmission line characteristics, especially the distributed capacitance and self–inductance of the trace — resulting in the reflection. It is a given that not all PCB traces can be straight, and so they will have to turn corners. Figure 8-3 shows progressively better techniques of rounding corners. Only the last example maintains constant trace width and minimizes reflections.

8.4.2 Layout Example

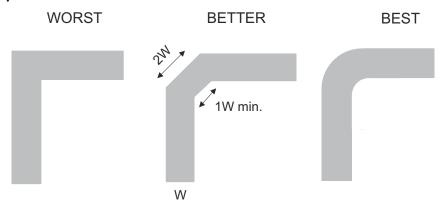


Figure 8-3. Trace Example

9 Device and Documentation Support

9.1 Documentation Support

9.1.1 Related Documentation

For related documentation, see the following:

· Texas Instruments, Implications of Slow or Floating CMOS Inputs

9.2 Receiving Notification of Documentation Updates

To receive notification of documentation updates, navigate to the device product folder on ti.com. Click on *Notifications* to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

9.3 Support Resources

TI E2E[™] support forums are an engineer's go-to source for fast, verified answers and design help — straight from the experts. Search existing answers or ask your own question to get the quick design help you need.

Linked content is provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's Terms of Use.

9.4 Trademarks

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9.5 Electrostatic Discharge Caution



This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

9.6 Glossary

TI Glossary

This glossary lists and explains terms, acronyms, and definitions.



10 Revision History

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

Changes from Revision M (November 2024) to Revision N (February 2025)	Page
Updated Section 1	
Removed Figure 5-4 and Figure 5-5	11
 Updated Section 7.1 	15
Updated Section 7.3	17
Updated Figure 8-1 to 5V VDD	19
Changes from Revision L (September 2023) to Revision M (November 2024)	Page
Updated the Typical Characteristics section	11
Added Figure 5-4 and Figure 5-5	11
Changes from Revision K (March 2023) to Revision L (September 2023)	Page
· Changed the format of the Package Information table to include package lead size	ze1
 Changed the format of the ESD Ratings, Electrical Characteristics, and AC Perfo 	ormance to consolidate
package specifications	5

11 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.





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PACKAGING INFORMATION

Orderable part number	Status (1)	Material type	Package Pins	Package qty Carrier	RoHS	Lead finish/ Ball material	MSL rating/ Peak reflow	Op temp (°C)	Part marking (6)
7901502EA	Active	Production	CDIP (J) 16	25 TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	7901502EA CD4052BF3A
8101801EA	Active	Production	CDIP (J) 16	25 TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	8101801EA CD4053BF3A
CD4051BE	Active	Production	PDIP (N) 16	25 TUBE	Yes	NIPDAU	N/A for Pkg Type	-55 to 125	CD4051BE
CD4051BEE4	Obsolete	Production	PDIP (N) 16	-	-	Call TI	Call TI	-55 to 125	CD4051BE
CD4051BF	Active	Production	CDIP (J) 16	25 TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	CD4051BF
CD4051BF3A	Active	Production	CDIP (J) 16	25 TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	CD4051BF3A
CD4051BM96	Active	Production	SOIC (D) 16	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-55 to 125	CD4051BM
CD4051BM96G3	Obsolete	Production	SOIC (D) 16	-	-	Call TI	Call TI	-55 to 125	CD4051BM
CD4051BM96G4	Obsolete	Production	SOIC (D) 16	-	-	Call TI	Call TI	-55 to 125	CD4051BM
CD4051BMT	Obsolete	Production	SOIC (D) 16	-	-	Call TI	Call TI	-55 to 125	CD4051BM
CD4051BNSR	Active	Production	SOP (NS) 16	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-55 to 125	CD4051B
CD4051BPW	Obsolete	Production	TSSOP (PW) 16	-	-	Call TI	Call TI	-55 to 125	CM051B
CD4051BPWR	Active	Production	TSSOP (PW) 16	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-55 to 125	CM051B
CD4051BPWRG4	Obsolete	Production	TSSOP (PW) 16	-	-	Call TI	Call TI	-55 to 125	CM051B
CD4052BE	Active	Production	PDIP (N) 16	25 TUBE	Yes	NIPDAU	N/A for Pkg Type	-55 to 125	CD4052BE
CD4052BEE4	Active	Production	PDIP (N) 16	25 TUBE	Yes	NIPDAU	N/A for Pkg Type	-55 to 125	CD4052BE
CD4052BF	Active	Production	CDIP (J) 16	25 TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	CD4052BF
CD4052BF3A	Active	Production	CDIP (J) 16	25 TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	7901502EA CD4052BF3A
CD4052BM	Obsolete	Production	SOIC (D) 16	-	-	Call TI	Call TI	-55 to 125	CD4052BM
CD4052BM96	Active	Production	SOIC (D) 16	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-55 to 125	CD4052BM
CD4052BM96G3	Obsolete	Production	SOIC (D) 16	-	-	Call TI	Call TI	-55 to 125	CD4052BM
CD4052BM96G4	Obsolete	Production	SOIC (D) 16	-	-	Call TI	Call TI	-55 to 125	CD4052BM
CD4052BMT	Obsolete	Production	SOIC (D) 16	-	-	Call TI	Call TI	-55 to 125	CD4052BM
CD4052BNSR	Active	Production	SOP (NS) 16	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-55 to 125	CD4052B
CD4052BPW	Obsolete	Production	TSSOP (PW) 16	-	-	Call TI	Call TI	-55 to 125	CM052B
CD4052BPWR	Active	Production	TSSOP (PW) 16	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-55 to 125	CM052B
CD4052BPWRG3	Obsolete	Production	TSSOP (PW) 16	-	-	Call TI	Call TI	-55 to 125	CM052B





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Orderable part number	Status	Material type	Package Pins	Package qty Carrier	RoHS	Lead finish/ Ball material (4) MSL rating/ Peak reflow (5)		Op temp (°C)	Part marking (6)
CD4052BPWRG4	Obsolete	Production	TSSOP (PW) 16	-	-	Call TI	Call TI	-55 to 125	CM052B
CD4053BE	Active	Production	PDIP (N) 16	25 TUBE	Yes	NIPDAU	N/A for Pkg Type	-55 to 125	CD4053BE
CD4053BF	Active	Production	CDIP (J) 16	25 TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	CD4053BF
CD4053BF3A	Active	Production	CDIP (J) 16	25 TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	8101801EA CD4053BF3A
CD4053BM	Obsolete	Production	SOIC (D) 16	-	-	Call TI	Call TI	-55 to 125	CD4053M
CD4053BM96	Active	Production	SOIC (D) 16	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-55 to 125	CD4053M
CD4053BM96G3	Obsolete	Production	SOIC (D) 16	-	-	Call TI	Call TI	-55 to 125	CD4053M
CD4053BM96G4	Obsolete	Production	SOIC (D) 16	-	-	Call TI	Call TI	-55 to 125	CD4053M
CD4053BMT	Obsolete	Production	SOIC (D) 16	-	-	Call TI	Call TI	-55 to 125	CD4053M
CD4053BNSR	Active	Production	SOP (NS) 16	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-55 to 125	CD4053B
CD4053BPW	Obsolete	Production	TSSOP (PW) 16	-	-	Call TI	Call TI	-55 to 125	CM053B
CD4053BPWR	Active	Production	TSSOP (PW) 16	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-55 to 125	CM053B
CD4053BPWRG3	Obsolete	Production	TSSOP (PW) 16	-	-	Call TI	Call TI	-55 to 125	CM053B
CD4053BPWRG4	Obsolete	Production	TSSOP (PW) 16	-	-	Call TI	Call TI	-55 to 125	CM053B

⁽¹⁾ Status: For more details on status, see our product life cycle.

⁽²⁾ **Material type:** When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

⁽³⁾ RoHS values: Yes, No, RoHS Exempt. See the TI RoHS Statement for additional information and value definition.

⁽⁴⁾ Lead finish/Ball material: Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

⁽⁵⁾ MSL rating/Peak reflow: The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

⁽⁶⁾ Part marking: There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

PACKAGE OPTION ADDENDUM

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Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

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OTHER QUALIFIED VERSIONS OF CD4051B, CD4051B-MIL, CD4052B, CD4052B-MIL, CD4053B, CD4053B-MIL:

Catalog: CD4051B, CD4052B, CD4053B

Automotive: CD4051B-Q1, CD4051B-Q1, CD4053B-Q1, CD4053B-Q1

Military: CD4051B-MIL, CD4052B-MIL, CD4053B-MIL

NOTE: Qualified Version Definitions:

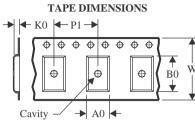
- Catalog TI's standard catalog product
- Automotive Q100 devices qualified for high-reliability automotive applications targeting zero defects
- Military QML certified for Military and Defense Applications



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TAPE AND REEL INFORMATION





A0	Dimension designed to accommodate the component width
В0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
CD4051BM96	SOIC	D	16	2500	330.0	16.4	6.5	10.3	2.1	8.0	16.0	Q1
CD4051BNSR	SOP	NS	16	2000	330.0	16.4	8.2	10.5	2.5	12.0	16.0	Q1
CD4051BNSR	SOP	NS	16	2000	330.0	16.4	8.2	10.5	2.5	12.0	16.0	Q1
CD4051BPWR	TSSOP	PW	16	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
CD4052BM96	SOIC	D	16	2500	330.0	16.4	6.5	10.3	2.1	8.0	16.0	Q1
CD4052BNSR	SOP	NS	16	2000	330.0	16.4	8.2	10.5	2.5	12.0	16.0	Q1
CD4052BNSR	SOP	NS	16	2000	330.0	16.4	8.2	10.5	2.5	12.0	16.0	Q1
CD4052BPWR	TSSOP	PW	16	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
CD4053BM96	SOIC	D	16	2500	330.0	16.4	6.5	10.3	2.1	8.0	16.0	Q1
CD4053BNSR	SOP	NS	16	2000	330.0	16.4	8.2	10.5	2.5	12.0	16.0	Q1
CD4053BNSR	SOP	NS	16	2000	330.0	16.4	8.2	10.5	2.5	12.0	16.0	Q1
CD4053BPWR	TSSOP	PW	16	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1



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*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
CD4051BM96	SOIC	D	16	2500	340.5	336.1	32.0
CD4051BNSR	SOP	NS	16	2000	353.0	353.0	32.0
CD4051BNSR	SOP	NS	16	2000	356.0	356.0	35.0
CD4051BPWR	TSSOP	PW	16	2000	367.0	367.0	35.0
CD4052BM96	SOIC	D	16	2500	356.0	356.0	35.0
CD4052BNSR	SOP	NS	16	2000	356.0	356.0	35.0
CD4052BNSR	SOP	NS	16	2000	353.0	353.0	32.0
CD4052BPWR	TSSOP	PW	16	2000	367.0	367.0	35.0
CD4053BM96	SOIC	D	16	2500	353.0	353.0	32.0
CD4053BNSR	SOP	NS	16	2000	353.0	353.0	32.0
CD4053BNSR	SOP	NS	16	2000	356.0	356.0	35.0
CD4053BPWR	TSSOP	PW	16	2000	367.0	367.0	35.0

PACKAGE MATERIALS INFORMATION

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TUBE



*All dimensions are nominal

Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	T (µm)	B (mm)
CD4051BE	N	PDIP	16	25	506	13.97	11230	4.32
CD4052BE	N	PDIP	16	25	506	13.97	11230	4.32
CD4052BEE4	N	PDIP	16	25	506	13.97	11230	4.32
CD4053BE	N	PDIP	16	25	506	13.97	11230	4.32
CD4053BEE4	N	PDIP	16	25	506	13.97	11230	4.32

D (R-PDS0-G16)

PLASTIC SMALL OUTLINE



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.006 (0,15) each side.
- Body width does not include interlead flash. Interlead flash shall not exceed 0.017 (0,43) each side.
- E. Reference JEDEC MS-012 variation AC.





SMALL OUTLINE PACKAGE



- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

 2. This drawing is subject to change without notice.

 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
- 5. Reference JEDEC registration MO-153.



SMALL OUTLINE PACKAGE



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SMALL OUTLINE PACKAGE



NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.



MECHANICAL DATA

NS (R-PDSO-G**)

14-PINS SHOWN

PLASTIC SMALL-OUTLINE PACKAGE



- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15.



14 LEADS SHOWN



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- C. This package is hermetically sealed with a ceramic lid using glass frit.
- D. Index point is provided on cap for terminal identification only on press ceramic glass frit seal only.
- E. Falls within MIL STD 1835 GDIP1-T14, GDIP1-T16, GDIP1-T18 and GDIP1-T20.

N (R-PDIP-T**)

PLASTIC DUAL-IN-LINE PACKAGE

16 PINS SHOWN



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Falls within JEDEC MS-001, except 18 and 20 pin minimum body length (Dim A).
- The 20 pin end lead shoulder width is a vendor option, either half or full width.





SOP



- 1. All linear dimensions are in millimeters. Dimensions in parenthesis are for reference only. Dimensioning and tolerancing
- per ASME Y14.5M.

 2. This drawing is subject to change without notice.

 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 mm, per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm, per side.



SOF



NOTES: (continued)

- 5. Publication IPC-7351 may have alternate designs.
- 6. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SOF



NOTES: (continued)

- 7. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 8. Board assembly site may have different recommendations for stencil design.



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